Panasonic

UNRF2A9

Silicon NPN epitaxial planar type

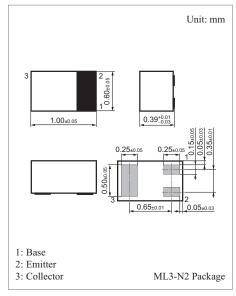
For digital circuits

■ Features

 Optimum for high-density mounting and downsizing of the equipment for Ultraminiature leadless package 0.6 mm × 1.0 mm (height 0.39 mm)

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	50	V	
Collector current	I_{C}	80	mA	
Total power dissipation	P _T	100	mW	
Junction temperature	T _j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	



Marking Symbol: 5C

Internal Connection

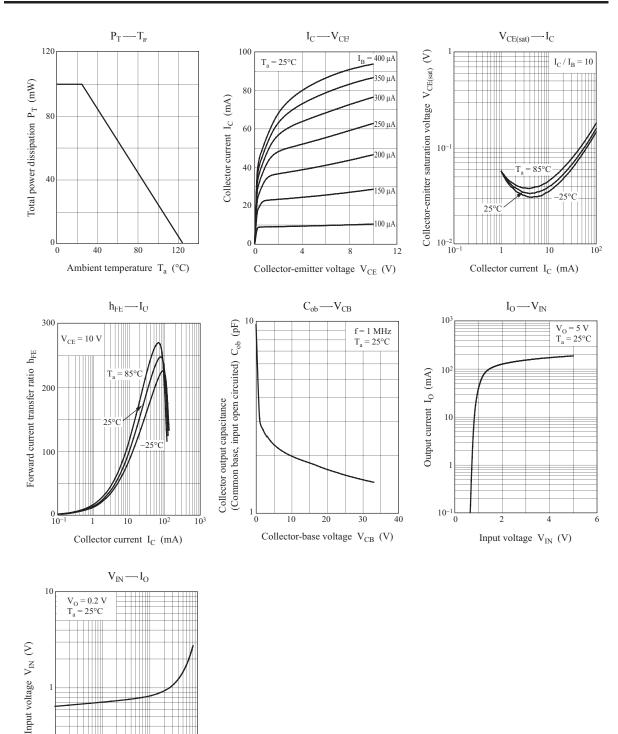
$$\begin{array}{c} R_1 \\ 1 \text{ k}\Omega \\ B \circ \longrightarrow W \\ R_2 \\ 10 \text{ k}\Omega \end{array} \circ C$$

■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_{\rm C} = 10 \; \mu A, I_{\rm H} = 0$	50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 50 \text{ V, } I_{E} = 0$			0.1	μА
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 50 \text{ V}, I_{B} = 0$			0.5	μА
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 6 \text{ V}, I_{C} = 0$			1.5	mA
Forward current transfer ratio	h _{FE}	$V_{CH} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	30			_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm CI} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$			0.25	V
Output voltage high-level	V _{OH}	$V_{CCI} = 5 \text{ V}, V_{B} = 0.5 \text{ V}, R_{LI} = 1 \text{ k}\Omega$	4.9			V
Output voltage low-level	V _{OL}	$V_{CCI} = 5 \text{ V}, V_B = 2.5 \text{ V}, R_{LI} = 1 \text{ k}\Omega$			0.2	V
Input resistance	R_1		-30%	1	+30%	kΩ
Resistance ratio	R_1 / R_2		0.08	0.1	0.12	_
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_{H} = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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Output current I_O (mA)

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